

Solutions to Exam Fall Semester 2019/2020

Problem 1: Wheatstone bridge linearization

[10pt]

The circuit in Fig. 1 is a linearized bridge, with $R + dR = R(1 + d) = R(1 + \alpha T)$, where T [°C] is the temperature and $\alpha = 0.004^\circ\text{C}^{-1}$ is the temperature coefficient.

1.1 DC analysis

[4pt]

- derive the output voltage as a function of the sensor resistance change dR ;

Let us write the current summation at nodes A and B (which are grounded), respectively:

$$\begin{cases} \frac{V_c}{R} + \frac{V_{ref}}{R} + \frac{V_{out}}{R_f} = 0; \\ \frac{V_c}{R+dR} + \frac{V_{ref}}{R} = 0; \end{cases} \quad (1)$$

leading to:

$$V_{out} = \frac{R_f \cdot dR}{R^2} V_{ref}. \quad (2)$$

- show the effects of the op-amp A_1 leakage currents I_p and I_m and of the two op-amps offset voltages at the output (assume the leakage currents of the op-amp A_2 are negligible).

Let us use the superposition principle in order to evaluate the effects of the leakage currents and the offsets voltages, referring to Fig. 1.

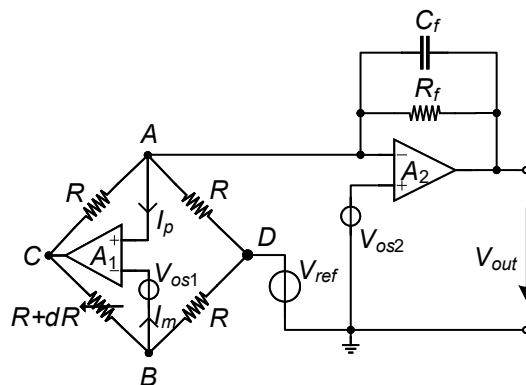


Figure 1: Linearized Wheatstone bridge. DC analysis set-up

Effect of the leakage currents I_p and I_m .

Let us write the current summation at nodes A and B (which are grounded) considering the leakage currents, respectively:

$$\begin{cases} \frac{V_c}{R} + \frac{V_{ref}}{R} + \frac{V_{out}}{R_f} - I_p = 0; \\ \frac{V_c}{R+dR} + \frac{V_{ref}}{R} - I_m = 0; \end{cases} \quad (3)$$

leading to:

$$V_{out} = (I_p - I_m) \cdot R_f + \frac{R_f \cdot dR}{R^2} (V_{ref} - I_m \cdot R). \quad (4)$$

Effect of A_1 offset voltage V_{os1} .

Let us write the current summation at nodes A and B considering the effect of A_1 offset voltage V_{os1} :

$$\begin{cases} \frac{V_c}{R} + \frac{V_{ref}}{R} + \frac{V_{out}}{R_f} = 0; \\ \frac{V_c - V_{os1}}{R+dR} + \frac{V_{ref} - V_{os1}}{R} = 0; \end{cases} \quad (5)$$

leading to:

$$V_{out} = -2 \frac{V_{os1} \cdot R_f}{R} + \frac{R_f \cdot dR}{R^2} (V_{ref} - V_{os1}). \quad (6)$$

Effect of A_2 offset voltage V_{os2} .

Let us write the current summation at nodes A and B considering the effect of A_2 offset voltage V_{os2} :

$$\begin{cases} \frac{V_c - V_{os2}}{R} + \frac{V_{ref} - V_{os2}}{R} + \frac{V_{out} - V_{os2}}{R_f} = 0; \\ \frac{V_c - V_{os2}}{R+dR} + \frac{V_{ref} - V_{os2}}{R} = 0; \end{cases} \quad (7)$$

leading to:

$$V_{out} = \left(1 + \frac{dR \cdot R_f}{R^2}\right) V_{os2} + \frac{R_f \cdot dR}{R^2} V_{ref}. \quad (8)$$

- rewrite the previous result in terms of output offset voltage (V_{off}) and relative gain error (ε), i.e. $V_{out} = V_{off} + dR \cdot G \cdot (1 - \varepsilon)$, where G is the gain in the ideal case (when $V_{off} = 0V$ and $\varepsilon = 0$).

Effects combination.

Summing up all of the previous effects leads to:

$$V_{out} = \underbrace{\frac{(I_p - I_m) \cdot R \cdot R_f + V_{os2} \cdot R - 2V_{os2} \cdot R_f}{R}}_{\text{offset error } V_{off}} + \frac{R_f \cdot dR}{R^2} V_{ref} \left(1 - \underbrace{\frac{I_m \cdot R + V_{os1} + V_{os2}}{V_{ref}}}_{\text{gain relative error } \varepsilon}\right). \quad (9)$$

1.2 Noise analysis

[4pt]

Assume $dR = 0$, the amplifier A_2 to be noiseless and the amplifier A_1 having no $1/f$ noise and only an input-referred thermal noise PSD given by $4kTR_A$.

For each of the noise sources calculate:

- the transfer function from the noise source to the output;
- the power spectral density and
- the output noise voltage variance.

For this calculation, V_{ref} is set to ground. Let us define $Z = C_f \parallel R_f$ and let us identify the 4 resistors in the bridge according to the names of their terminal nodes, i.e. R_{AC} , R_{AD} , R_{CB} and R_{BD} . Let us model the noise sources of the amplifier A_1 and the resistors in the bridge as a voltage source and the noise source of R_f as a current source as shown in Fig. 2.

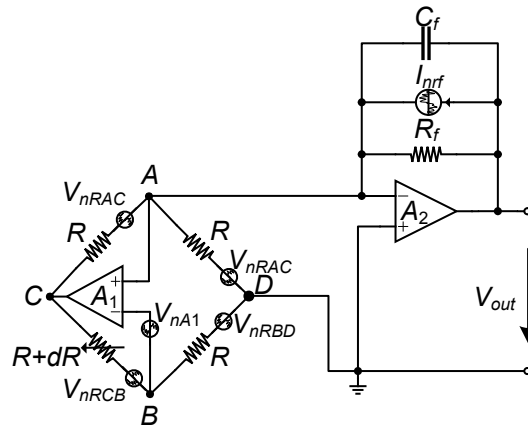


Figure 2: Linearized Wheatstone bridge. Noise analysis set-up

Let us use the superposition principle in order to evaluate the noise contributions.

Contribution of R_{AC} noise source $V_{n,RAC}$

Let us write the current summation at nodes A and B considering the noise source $V_{n,RAC}$. In this case, the node A , D and B (due to the virtual ground principle) are grounded:

$$\begin{cases} \frac{V_C - V_{n,RAC}}{R} + \frac{V_{out}}{Z} = 0; \\ \frac{V_C}{R} = 0; \end{cases} \quad (10)$$

leading to:

$$H_{n,RAC}(s) \triangleq V_{n,out} = \frac{Z}{R} V_{n,RAC} = \frac{R_f}{R} \frac{1}{1 + sC_f R_f} V_{n,RAC}; \quad (11)$$

which is a first order low-pass filters transfer function with gain R_f/R and $\omega_c = 1/(R_f C_f)$, therefore the noise equivalent-bandwidth is:

$$\Delta f = \frac{1}{4R_f C_f}; \quad (12)$$

the output noise variance is:

$$\overline{V_{out,RAC}^2} = (4kTR) \cdot \left(\frac{R_f}{R}\right)^2 \cdot \frac{1}{4R_f C_f} = \frac{kT}{C_f} \cdot \frac{R_f}{R}; \quad (13)$$

where T is the absolute temperature, k is the Boltzmann constant and $(4kTR)$ is the resistor PSD.

Contribution of R_{AD} noise source $V_{n,RAD}$

Let us write the current summation at nodes A and B considering the noise source $V_{n,RAD}$. In this case, the node A , D and B (due to the virtual ground principle) are grounded:

$$\begin{cases} \frac{V_c}{R} - \frac{V_{n,RAD}}{R} + \frac{V_{out}}{Z} = 0; \\ \frac{V_c}{R} = 0; \end{cases} \quad (14)$$

leading to:

$$H_{n,RAD}(s) \triangleq V_{n,out} = \frac{Z}{R} V_{n,RAD} = \frac{R_f}{R} \frac{1}{1 + sC_f R_f} V_{n,RAD}. \quad (15)$$

The power spectral density is given by:

$$S_{V_{n,RAD}}(f) = |H_{n,RAD}(s)|^2 4kTR \quad (16)$$

$H_{n,RAD}(s)$ is a first order low-pass filters transfer function with gain R_f/R and $\omega_c = 1/(R_f C_f)$, therefore the noise equivalent-bandwidth is:

$$\Delta f = \frac{1}{4R_f C_f}; \quad (17)$$

the output noise variance is:

$$\overline{V_{out,RAD}^2} = (4kTR) \cdot \left(\frac{R_f}{R}\right)^2 \cdot \frac{1}{4R_f C_f} = \frac{kT}{C_f} \cdot \frac{R_f}{R}; \quad (18)$$

where T is the absolute temperature, k is the Boltzmann constant and $(4kTR)$ is the resistor PSD.

Contribution of R_{CB} noise source $V_{n,RCB}$

Let us write the current summation at nodes A and B considering the noise source $V_{n,RCB}$. In this case, the node A , D and B (due to the virtual ground principle) are grounded:

$$\begin{cases} \frac{V_c}{R} + \frac{V_{out}}{Z} = 0; \\ \frac{V_c - V_{n,RCB}}{R} = 0; \end{cases} \quad (19)$$

leading to:

$$H_{n,RCB}(s) \triangleq V_{n,out} = \frac{Z}{R} V_{n,RCB} = \frac{R_f}{R} \frac{1}{1+sC_fR_f} V_{n,RCB}. \quad (20)$$

The power spectral density is given by:

$$S_{V_{n,RCB}}(f) = |H_{n,RCB}(s)|^2 4kTR \quad (21)$$

$H_{n,RCB}(s)$ is a first order low-pass filters transfer function with gain R_f/R and $\omega_c = 1/(R_f C_f)$, therefore the noise equivalent-bandwidth is:

$$\Delta f = \frac{1}{4R_f C_f}; \quad (22)$$

the output noise variance is:

$$\overline{V_{out,RCB}^2} = (4kTR) \cdot \left(\frac{R_f}{R}\right)^2 \cdot \frac{1}{4R_f C_f} = \frac{kT}{C_f} \cdot \frac{R_f}{R}; \quad (23)$$

where T is the absolute temperature, k is the Boltzmann constant and $(4kTR)$ is the resistor PSD.

Contribution of R_{BD} noise source $V_{n,RBD}$

Let us write the current summation at nodes A and B considering the noise source $V_{n,RBD}$. In this case, the node A , D and B (due to the virtual ground principle) are grounded:

$$\begin{cases} \frac{V_c}{R} + \frac{V_{out}}{Z} = 0; \\ \frac{V_c}{R} + \frac{V_{n,RBD}}{R} = 0; \end{cases} \quad (24)$$

leading to:

$$H_{n,RBD}(s) \triangleq V_{n,out} = \frac{Z}{R} V_{n,RBD} = \frac{R_f}{R} \frac{1}{1+sC_fR_f} V_{n,RBD}. \quad (25)$$

The power spectral density is given by:

$$S_{V_{n,RBD}}(f) = |H_{n,RBD}(s)|^2 4kTR \quad (26)$$

$H_{n,RBD}(s)$ is a first order low-pass filters transfer function with gain R_f/R and $\omega_c = 1/(R_f C_f)$, therefore the noise equivalent-bandwidth is:

$$\Delta f = \frac{1}{4R_f C_f}; \quad (27)$$

the output noise variance is:

$$\overline{V_{out,RBD}^2} = (4kTR) \cdot \left(\frac{R_f}{R}\right)^2 \cdot \frac{1}{4R_f C_f} = \frac{kT}{C_f} \cdot \frac{R_f}{R}; \quad (28)$$

where T is the absolute temperature, k is the Boltzmann constant and $(4kTR)$ is the resistor PSD.

Contribution of A_1 noise source $V_{n,A1}$

Let us write the current summation at nodes A and B considering the noise source $V_{n,A1}$. In this case, the node A and D are grounded:

$$\begin{cases} \frac{V_C}{R} + \frac{V_{out}}{Z} = 0; \\ \frac{V_C - V_{n,A1}}{R} - \frac{V_{n,A1}}{R} = 0; \end{cases} \quad (29)$$

leading to:

$$H_{n,A1}(s) \triangleq V_{n,out} = -2 \frac{Z}{R} V_{n,A1} = -2 \frac{R_f}{R} \frac{1}{1 + sC_f R_f} V_{n,A1}. \quad (30)$$

The power spectral density is given by:

$$S_{V_{n,A1}}(f) = |H_{n,A1}(s)|^2 4kTR_A \quad (31)$$

$H_{n,A1}(s)$ is a first order low-pass filters transfer function with gain $-2R_f/R$ and $\omega_c = 1/(R_f C_f)$, therefore the noise equivalent-bandwidth is:

$$\Delta f = \frac{1}{4R_f C_f}; \quad (32)$$

the output noise variance is:

$$\overline{V_{out,A1}^2} = (4kTR_A) \cdot \left(-2 \frac{R_f}{R}\right)^2 \cdot \frac{1}{4R_f C_f} = \frac{kT}{C_f} 4 \frac{R_A R_f}{R^2}; \quad (33)$$

where T is the absolute temperature, k is the Boltzmann constant and $(4kTR_A)$ is the amplifier PSD.

Contribution of R_f noise source $I_{n,Rf}$

Let us write the current summation at nodes A and B considering the noise source $V_{n,RBD}$. In this case, the node A , D and B (due to the virtual ground principle) are grounded:

$$\begin{cases} \frac{V_C}{R} + \frac{V_{out}}{Z} - I_{n,Rf} = 0; \\ \frac{V_C}{R} = 0; \end{cases} \quad (34)$$

leading to:

$$H_{n,Rf}(s) \triangleq V_{n,out} = I_{n,Rf} \cdot Z = \frac{R_f}{1 + sC_f R_f} I_{n,Rf}. \quad (35)$$

By replacing $I_{n,Rf} = V_{n,Rf}/R_f$:

$$H_{n,Rf}(s) = \frac{1}{1 + sC_f R_f} V_{n,Rf}. \quad (36)$$

The power spectral density is given by:

$$S_{V_n, Rf}(f) = |H_{n, A1}(s)|^2 4kTR_f \quad (37)$$

$H_{n, Rf}(s)$ is a first order low-pass filters transfer function with gain 1 and $\omega_c = 1/(R_f C_f)$, therefore the noise equivalent-bandwidth is:

$$\Delta f = \frac{1}{4R_f C_f}; \quad (38)$$

the output noise variance is:

$$\overline{V_{out, Rf}^2} = (4kTR_f) \cdot \frac{1}{4R_f C_f} = \frac{kT}{C_f}; \quad (39)$$

where T is the absolute temperature, k is the Boltzmann constant and $(4kTR_f)$ is the resistor PSD.

Finally,

- calculate the total output noise voltage variance.

By summing up the previous noise variance contributions:

$$\overline{V_{out, n}^2} = \frac{kT}{C_f} \left(4 \frac{R_f}{R} + 4 \frac{R_f R_A}{R^2} + 1 \right) \quad (40)$$

1.3 Dimensioning the system

[4pt]

Assuming ideal op-amps and $V_{REF} = 1V$ calculate R , R_f and C_f to achieve:

- an output temperature-to-voltage gain G_T of $0.2V/^\circ C$ near $0^\circ C$;
- a cut-off frequency $f_c = 1kHz$ and
- an output noise voltage variance of $100 \mu V_{RMS}$ at $T = 0^\circ C = 273K$, knowing that $k = 1.3807 \times 10^{-23} J/K$.

The design specifications can be translated in the following system with three equations and three unknowns (R , R_f and C_f):

$$\begin{cases} G_T = \frac{R_f \cdot V_{ref} \cdot \alpha}{R} = 0.2V/^\circ C \\ f_c = \frac{1}{2 \cdot \pi \cdot R_f \cdot C_f} = 1kHz \\ \overline{V_{out, n}^2} = \frac{kT}{C_f} \left(4 \frac{R_f}{R} + 1 \right) = (100 \mu V_{RMS})^2; \end{cases} \quad (41)$$

From the first equation we get that:

$$\frac{Rf}{R} = \frac{G_T}{V_{ref} \cdot \alpha} = 50. \quad (42)$$

By replacing this quantity into the third equation, the value of C_f can be calculated:

$$C_f = \frac{kT}{V_{out,n}^2} \left(4 \frac{R_f}{R} + 1 \right) = 76 \text{ pF.} \quad (43)$$

Then C_f can be replaced into the second equation to easily get $R_f = 21 \text{ M}\Omega$. Finally, $R = R_f/50 = 420 \text{ k}\Omega$

To summarize: $C_f = 76 \text{ pF}$, $R_f = 21 \text{ M}\Omega$ and $R = 420 \text{ k}\Omega$.